NSN 5961-01-619-6309

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-619-6309 **Inclosure Material:** Ceramic **Overall Length:** 94.0 millimeters **Overall Height:** 70.0 millimeters **Overall Width:** 54.0 millimeters **Mounting Facility Quantity: Mounting Method: Bracket Product Name:** Three phase rectifier bridge **Special Features:** Isolation voltage 3000v, blocking voltage up to 1800v, op temp: -40 degrees to 125 degrees c Shelf Life: N/a **Unit Of Measure: Demilitarization:**